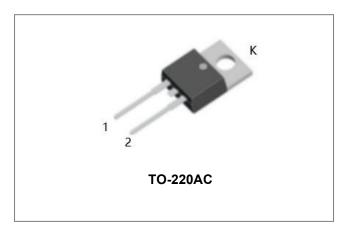






## 19TQ015CJ SCHOTTKY RECTIFIER



# Circuit Diagram



### **Features**

- 100 °C T<sub>J</sub> operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced
- · mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- · Terminals finish: Tin Lead-free plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

### Maximum Ratings@Tc=25°C unless otherwise specified

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage	V <sub>RRM</sub> V <sub>RWM</sub>	-	15	V
DC Blocking Voltage	V <sub>R</sub>			
Average Rectified Forward Current	I <sub>F (AV)</sub>	50 % duty cycle at T <sub>C</sub> = 80 °C, rectangular waveform	19	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse	120	Α

### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@ 19A, Pulse, T <sub>A</sub> = 25 °C @ 38A, Pulse, T <sub>A</sub> = 25 °C	0.34 0.42	0.36 0.46	V
Reverse Current*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 25 °C	4	10.5	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25  ^{\circ}C$ $f_{SIG} = 1MHz$	1270	2500	pF
Series Inductance	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

<sup>\*</sup> Pulse width < 300 μs, duty cycle < 2%



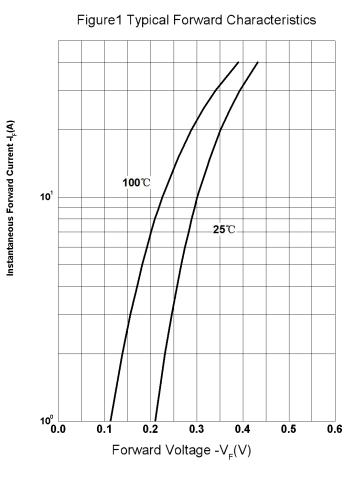


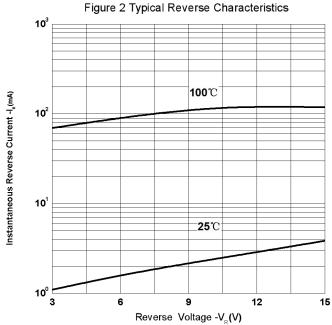


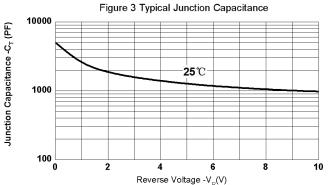
### **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +100	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +100	°C
Typical Thermal Resistance Junction to Case	Rejc	DC operation	1.5	°C/W
Approximate Weight	wt	-	1.6	g
Case Style	TO-220AC			

## **Ratings and Characteristics Curves**







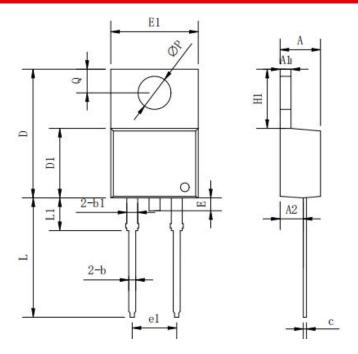
- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •





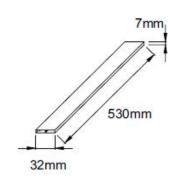


### **Mechanical Dimensions TO-220AC**

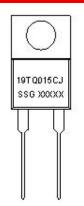


Symbol	Dimensions in millimeters			
	Min	Typical	Max	
Α	3.56	-	4.83	
A1	0.51	-	1.4	
A2	2.03	-	2.92	
b	0.38	-	1.02	
b1	1.14	-	1.78	
С	0.31	-	0.61	
D	14.22	-	16.51	
D1	8.38	-	9.42	
E	9.65	-	10.67	
е	-	2.54	-	
e1	-	5.08	-	
H1	5.84	-	6.86	
L	12.7	-	14.73	
L1	-	-	6.35	
ФР	-	3.56	-	
Q	2.54	-	3.43	

## **Tube Specification**



## **Marking Diagram**



Where XXXXX is YYWWL

19TQ015CJ = Part Name SSG = SSG YY = Year WW = Week L = Lot Number

Cautions: Molding resin
Epoxy resin UL:94V-0

## **Ordering Information**

Device	Package	Shipping	
19TQ015CJ	TO-220AC (Pb-Free)	50 pcs/ tube	

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •







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